NSN 5961-00-261-8880

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-261-8880 **Inclosure Material:** Glass **Overall Length:** 0.175 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.075 inches **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 0.5 breakdown voltage, dc **Current Rating Per Characteristic:** 250.00 milliamperes all primaries preset **Power Rating Per Characteristic:** 125.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Special Features:** Point contact - rf detector **Precious Material And Location:** Terminal surface option gold **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No Fiig: A110a0